Ultrafast electron dynamics in platinum and gold thin films driven by optical and terahertz fields

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We investigate the ultrafast electron dynamics triggered by terahertz and optical pulses in thin platinum and gold films by probing their transient optical reflectivity. The response of the platinum film to an intense terahertz pulse is similar to the optically-induced dynamics of both films and can be described by a two-temperature model. Surprisingly, gold exhibits a much smaller terahertz pulse-induced reflectivity change and with opposite sign. For platinum, we estimate a 20% larger electron-phonon coupling for the terahertz-driven dynamics compared to the optically-induced one, which we ascribe to an additional nonthermal electron-phonon coupling contribution. We explain the remarkable response of gold to terahertz field as the field emission of electrons due to Fowler-Nordheim tunneling. Our results provide a fundamental insight into the ultrafast processes relevant to modern electro- and magneto-optical applications.

The advent of intense single-cycle terahertz (THz) radiation sources has opened new avenues for the exploration of light-matter interaction, thanks to the large accessible electric fields of the order of MV/cm at photon energies in the meV range. With the emergence of intense table-top THz sources, it is now possible to study, in a laboratory setting, THz driven ultrafast dynamics of coupled degrees of freedom in condensed matter systems.[12] Efforts underway are aiming at reaching local electric field strengths of the order of 100 MV/cm (1 V/Å), comparable to that of the interatomic fields using near-field enhancement in metamaterials.[6] Metals provide an excellent medium to investigate THz-induced coupled many-body dynamics, thanks to the presence of multiple degrees of freedom able to interact with THz radiation, including free electrons, phonons, and magnons in magnetic materials. A variety of THz-driven physical processes ranging from ultrafast demagnetization in magnetic thin films[2] to field emission in nanotips have been recently reported in the literature,[13,14] which were earlier on observed only in the optical regime.[12] Now, thanks to the availability of intense THz sources, it is possible to compare the dynamics induced by light pulses in two regions of electromagnetic spectrum that differ in frequency by three orders of magnitude. This is expected to provide an unprecedented insight into phenomena involving light-matter interaction.[11]

Optically-induced ultrafast dynamics in metals is usually discussed using a phenomenological two-temperature model (2TM).[15] This model is in principle applicable to dynamics driven by THz radiation as well, since it does not rely on the specific mechanism of excitation but only on the total energy deposited. According to the 2TM model, ultrafast pulses directly excite energetic electrons, which within tens of femtoseconds thermalize via electron-electron collisions to a Fermi-Dirac distribution at high temperature. Then, the hot electrons transfer energy to the lattice over the characteristic electron-phonon coupling time. One of the major assumptions of the model is that the thermalization of electrons is much faster than the electron-phonon coupling time. However, time-resolved photoemission spectroscopy measurements have shown that this assumption is not always valid in all materials, and that a nonequilibrium electron population can exist for up to 1 ps for materials such as gold.[15,16] In contrast to optical excitation several eV away from the Fermi level $E_F$, the energy $E$ of electrons excited by THz pumping is within a few meV from $E_F$. In standard Landau’s Fermi liquid theory, such electrons are expected to thermalize significantly slower than those excited by the optical pulses since $\tau^{-1} \sim (E - E_F)^2$, see Refs.[15,16] However, more refined models of ultrafast electron dynamics include also a temperature dependent term which prevents an indefinite slowdown of the relaxation for very low photon energies.[15] Therefore, experiments in the THz regime can provide new insights into the thermalization mechanism of metals beyond the 2TM model.

In this Letter, we compare the dynamics induced by THz and near-infrared radiation in platinum and gold thin films, two metals that are neighbors in the periodic table but have very different band structures. Both materials are of a broad current interest in condensed matter physics.[17] Platinum is widely used in magnetic and magneto-optical experiments due to its large spin-orbit coupling, whereas gold is essential in plasmonics and for the fabrication of metamaterials thanks to its low ohmic losses. By performing time-resolved reflectivity measurements using 800 nm probe pulses, and by simulating the dynamics using a 2TM, we gain a detailed understanding of the dynamics at play, which we expect to be also relevant to other metals with similar electronic configuration.

The 800 nm pump-probe experiments were performed with an amplified Ti:sapphire laser, with a pulse duration of approximately 55 fs and a repetition rate of 1 kHz. We chose orthogonal polarization between the pump (s-polarized) and the probe (p-polarized) beams to eliminate the coherent artifacts.
which arise in the interference between energy-degenerate pulses. The pump was incident at an angle $\theta_{\text{pump}} = 10$ degrees and the probe at an angle $\theta_{\text{probe}} = 45$ degrees, as shown in Fig. 1(a). The temporal profile of the pulse intensity measured using an autocorrelator is shown in Fig. 1(b).

The intense single-cycle THz pump required for the THz pump-optical probe experiment was generated in the organic crystal DSTMS by the optical rectification of 1560 nm radiation, which was down-converted from the 800 nm fundamental using an optical parametric amplifier. The temporal profile of the electric field of the THz pump, determined by electro-optic sampling in a GaP crystal, was characterized by a peak amplitude of approximately 1 MV/cm, as shown in Fig. 1(c). The incident fluence was estimated to be around 2.5 mJ/cm$^2$ for both THz and 800 nm pumps. The change in reflectivity of the 800 nm probe was measured using a silicon photo-detector. For both experiments, the pump was modulated with a chopper at half the laser repetition rate.

Fig. 2(a)-(b) show the transient reflectivity in platinum and, respectively, gold. For both materials, the reflectivity change caused by the THz pump is shown by gray symbols, while that caused by the 800 nm pump is shown by orange symbols. The continuous lines show the temperature evolution calculated using the 2TM model described in the text, with the temperature scale shown on the right axis. The insets represent the simulated absorption profile in the for the two pump wavelengths.

<table>
<thead>
<tr>
<th>Material</th>
<th>$G_{\text{THz}}$ (W/m$^3$K)</th>
<th>$G_{800}$ (W/m$^3$K)</th>
<th>$G_{\text{Ref}[24\text{--}27]}$ (W/m$^3$K)</th>
</tr>
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<tbody>
<tr>
<td>Platinum</td>
<td>$(11.2\pm0.1)\times10^{17}$</td>
<td>$(9.3\pm0.1)\times10^{17}$</td>
<td>$(2.5\text{-}11)\times10^{17}$</td>
</tr>
<tr>
<td>Gold</td>
<td>$(2.2\pm0.1)\times10^{16}$</td>
<td>$(2.1\pm0.3)\times10^{16}$</td>
<td></td>
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ligible, and becomes effective only after they thermalize. Mal electrons are far from the Fermi level, so the contribution of electron-phonon coupling at the Fermi level are those contributing the most to the electron dynamics. For both the 800 nm and THz pumps, a relatively large fraction of electrons excited by the electromagnetic field have $d$ character, which have a relatively large scattering cross sections with phonons. For the case of terahertz fields, the characteristic energy of the excited electrons is lower, and consequently the contribution of electron-phonon scattering is larger, explaining the observed $G_{THz} > G_{800}$.

For the case of gold, the situation is remarkably different. The phonon DOS is similar to that of platinum, as shown in Fig. 3(b). However, the electronic DOS is substantially different. In particular, the density of states within about 1 eV from the Fermi level is dominated by itinerant $s$-states, with a negligible contribution from the localized $d$-states. The electronic DOS for gold around the Fermi level is much smaller than that for platinum, which is consistent with the much smaller electron-phonon coupling extracted from the transient reflectivity. However, this observation by itself does not provide an explanation for neither the much weaker THz-induced reflectivity change, nor its opposite sign compared to the 800 nm pump, which is the most striking result in Fig. 2. We note in particular that for thermalized electrons, a THz-induced increase of the transient reflectivity would imply a decrease of temperature, in an apparent violation of the principle of the conservation of energy. On the other hand, the 2TM simulations show comparable electronic temperature change for both optical and THz pumps (Fig. 3(b)), suggesting that a mechanism other than thermalization must be at play.

We argue that our observations can be explained by the emission from the gold film of electrons accelerated by the strong THz field. Qualitatively, this mechanism can be explained assuming that the electric field of the THz pump tilts the potential barrier, enabling electron tunneling through it into vacuum, without sample heating. Electron emission has already been observed in nano-tips and metallic metasurfaces made of gold, tungsten etc. [31-34], where the local enhancement of the THz electric field helps reaching the threshold of emission. More recently, THz-driven electron emission was observed from a gold surface using a peak electric field as low as 50 kV/cm and without any local enhancement, although the thickness and other film characteristics were not reported [35,36].

The observation of field emission in ultrathin gold films deposited on a solid substrate is however still missing, and it is this geometry that is the most relevant for many applications.

Field-induced electron emission is explained by the Fowler-Nordheim model of quantum mechanical tunneling [37]. The probability of field emission for THz electric field of frequency $f$ and peak amplitude $E_{THz}$ is related to the value of Keldysh parameter $\gamma = 2 \pi f \sqrt{2 m e^2}/eE_{THz}$, where $\phi$, $m$, and $e$ are the the work function, the mass, and the charge of the electron, respectively. Field emission is dominant for $\gamma \ll 1$, whereas photoionization is dominant for $\gamma \gg 1$. For gold, and using our electric field values and work function $\phi = 5.2$ eV as given in the literature, $\gamma \approx 1.2$. In this regime, when $\gamma \approx 1$ which physical effect would be dominant is less clear. However, Uiberacker et al. [38] have reported field emission for a value of Keldysh parameter as high as three.

We apply these general observations to first to the case of platinum, where the two excitations give rise to similar dynamics. For both the 800 nm and THz pumps, a relatively large fraction of electrons excited by the electromagnetic field have $d$ character, which have a relatively large scattering cross sections with phonons. For the case of terahertz fields, the characteristic energy of the excited electrons is lower, and consequently the contribution of electron-phonon scattering is larger, explaining the observed $G_{THz} > G_{800}$.

To gain insight into the mechanisms giving rise to transient reflectivity variations in Fig. 2, we zoom in on the initial transient response of gold to the terahertz pump. By overlaying on that curve the square of the THz electric field $E_{THz}$ shown in Fig. 3(c), it is clear that the time profile of initial transient reflectivity follows $E_{THz}^2$. Since the Fowler-Nordheim tunneling current is also proportional to $E_{THz}^2$, experimental setup.

FIG. 3. (a) Electronic and (b) phonon density of states (DOS) for platinum and gold. The calculated DOS are taken from Refs. [29,30]. The orange and gray shading illustrate the maximum bandwidth of the nonthermal electrons excited by the 800 nm and, respectively, THz pumps.
this further supports the argument that the THz induced transient reflectivity in gold is dominated by electron field emission. The sign of the effect, i.e. the transient increase of the reflectivity in the first 500 fs, is expected when the plasma frequency decreases. This is in turn expected in a Drude-Lorentz picture when the electron density reduces, as it would be the case for the electron field emission. The rather laborious algebraic derivation is presented in the Supplemental Material.

In addition, we also observe a rectification behavior which we model with a Gaussian-like shape mimicking the terahertz field carrier envelope. This rectification behavior flips its sign when we change the polarization of the THz pump pulse by 180 degrees, as shown in the inset of Fig. 4. This rectification effect can be thought as the net normal component of the THz electric field arising due to slight asymmetry of the film interfaces (air/gold and gold/substrate). The subsequent decrease of reflectivity at later times can be understood as the consequence of the thermalization of electrons that with the lattice, as observed in all other measurements shown in Fig. 1. However, the effect is now significantly reduced, since most of the energy from the radiation has already been transferred into kinetic energy of the emitted electrons which have left the sample. A good fit to the data is obtained when the three effects: electron field emission, rectification and thermalization are considered.

Field emission is expected to be negligible amplitude for pump wavelengths in the visible and near-infrared range. Indeed, for visible photons, $\gamma$ is two orders of magnitude larger than for the terahertz case, hence the corresponding emission is much less probable. The field emission probability decreases also with the character of the accelerated electrons. Theoretically, the tunneling probability for $d$-electrons is approximately three orders of magnitude lower than that of $s$-electron with the same energy. This can be understood with a larger scattering cross section for $d$-electrons that cannot be accelerated at large enough energies before undergoing a scattering event and thermalize with the lattice. Pt has a relative large density of $d$-states around the Fermi level, as shown in Fig. 3(a), and hence electron field emission is not expected in this material. Finally, we comment on the fact that the deposited terahertz energy, and hence the related dynamics, depends strongly on the thickness of the sample. We show in the Supplemental Material, that little energy is deposited in 50 nm thick platinum and gold films, in turn resulting in much reduced or undetectable transient reflectivity. Our results are then valid for films which have thickness on the order of 10 nm or less, which are the most relevant for current research and applications. It has to be noted that for gold 10 nm is also the percolation threshold thickness, and a possible local field enhancement could aid the field emission process.

In summary, we studied the THz and 800 nm induced electron and lattice dynamics in gold and platinum thin films measuring their transient optical reflectivity. Platinum showed comparable response to both THz and optical pumps, with a 2TM simulation returning a 20% larger electron-phonon coupling $G$ when the material excited by terahertz fields. We suggest that this can be understood introducing an additional coupling channel only available when nonthermal electrons are present close to the Fermi level, which is the case for terahertz radiation but not for near-infrared light. Hence, our results suggest that the common assumption of wavelength-independent $G$ is not strictly correct when wavelengths which differs by orders of magnitude are considered. Gold showed also a response consistent with the 2TM when driven with 800 nm excitation. However, we found that such model breaks down the material is excited with intense terahertz fields. We argue that such behavior can be explained in terms of electronic field emission within the Fowler-Nordheim model, supported by a reasonably small Keldysh parameter and a positive transient reflectivity which varies as the square of the incident terahertz field. The much larger fraction of $s$-states near the Fermi level in gold, as compared to platinum, makes this mechanism the dominant effect in this case, while electron-phonon scattering dominates in platinum. We anticipate that our results will be highly relevant for many current ultrafast experiments in magnetism and optics where platinum, gold or metallic thin films with similar properties are incorporated as a part of heterostructures or metamaterials.

See the supplementary material for (i) two-temperature model simulations; (ii) sample characterization using THz time-domain spectroscopy; (iii) derivation of the relationship between transient optical reflectivity and material properties; and (iv) THz transient reflectivity in 50 nm films.

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![THz Electric Field](image_url)
DATA AVAILABILITY

The data that support the findings of this study are available from the corresponding author upon reasonable request.